



Densest-Packed Columnar Structures of Hard Spheres: An Investigation of the Structural Dependence of Electrical Conductivity

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Identical hard spheres in cylindrical confinement exhibit a rich variety of densest-packed columnar structures. Such structures, which generally vary with the corresponding cylinder-to-sphere diameter ratio D , serve as structural models for a variety of experimental systems at the micro- or nano-scale. In this research, the electrical conductivity as a function of D has been studied for four different types of such columnar structures. It was found that, for increasing D , the electrical conductivity of each type of structures decreases monotonously, as a result of the system's resistive components becoming more densely packed along the long axis of the cylindrical space. However, there exists a discontinuous rise in the system's electrical conductivity at $D = 1 + \sqrt{3}/2$ (discontinuous zigzag-to-single-helix transition) and $D = 2$ (discontinuous double-helix-to-double-helix transition), respectively, as a result of the establishment of additional conducting paths upon an abrupt increase in the number of inter-particle contacts. This is not the case for the continuous single-helix-to-double-helix transition at $D = 1 + 4\sqrt{3}/7$. The results, which tell us how the system's electrical conductivity can be tuned through a variation of D , could serve as a guide for the development of quasi-one-dimensional materials with a structurally tunable electrical conductivity.

Keywords: packing, structure, conductivity, resistor network, sphere, helix, zigzag, confinement

1 INTRODUCTION

Packing problems [1], which concern the optimal arrangements of objects in space, have historically been of great interest to both physicists and mathematicians. Such problems not only pose sufficient intellectual challenges for mathematicians [2], but they also yield solutions that physicists can use as theoretical models to understand the structures of matter [3–6]. Prominent examples include the application of the face-centered cubic (fcc) and hexagonal close-packed (hcp) structures as models for bulk crystal structures of solids [4] and the application of random close packings as models for bulk amorphous structures of liquids [3, 6]. In contrast to these examples for bulk systems, the past few decades have seen an uprising interest in the packings of particles in confined settings, such as those of particles confined within a two-dimensional box [7, 8], within a parallel strip [9–14], within a spherical container [15, 16], within a cylindrical container [17–36], onto a cylindrical surface [37], between parallel plates [38–46], within a wedge cell [47, 48], or within a flexible container [49]. In particular, for packings of identical spheres in cylindrical confinement, more than fifty densest-packed columnar structures have been discovered within a relatively narrow range of the cylinder-to-

sphere diameter ratio D [17, 22, 24, 29, 30] where, intriguingly, many of such columnar structures exhibit unexpected chirality despite the simplicity of the confining cylindrical geometry. On the other hand, such columnar structures of spheres have been observed for a variety of experimental systems at both the micro- [50–56] and the nano-scale [57–63]. This problem of confined packings has recently been extended to shape-anisotropic particles [13, 14, 36, 37], for which a variety of confinement-induced crystal structures with specific orientational order have been discovered.

The research described above focussed on the structural aspects of the corresponding densest-packed arrangements of particles. For each densest-packed structure, those studies mainly involved a characterisation of the packing fraction and contact network and an investigation of the underlying mechanism of confinement-induced geometric frustration. Not only have the theoretical findings helped us understand better the structural properties of some existing experimental systems; they can also serve as a basis for the design of quasi-one-dimensional materials with designated physical properties. From the viewpoint of materials design, however, it is also important to understand how the macroscopic mechanical, electrical or optical properties of a system depend on the microscopic arrangements of its constituents, because an understanding of such structure-property relationships would allow those macroscopic properties to be tailored via a controlled microscopic assembly of the system's constituents. Following this spirit, we have investigated how the electrical conductivity of a densest-packed columnar structure of identical spheres in cylindrical confinement depends on the underlying microscopic arrangement of spheres and how this property varies with the cylinder-to-sphere diameter ratio D . The structures investigated were the zigzag structures at $D \in (1, 1 + \sqrt{3}/2)$, the single-helix structures at $D \in (1 + \sqrt{3}/2, 1 + 4\sqrt{3}/7)$, the double-helix structures at $D \in (1 + 4\sqrt{3}/7, 2)$, and the double-helix structures at $D \in (2, 1 + 3\sqrt{3}/5)$. Based on a resistor-network model [64–68] and certain symmetry considerations, an analytic expression that describes the electrical conductivity σ as a function of D has been derived for each type of structures. The results, which tell us how the system's electrical conductivity can be tuned through a variation of D , could serve as a guide for the development of quasi-one-dimensional materials with a structurally tunable electrical conductivity.

This paper is organized as follows: In **Section 2**, we introduce the resistor-network model [67] as employed in our study of electrical conductivity. In **Sections 3–5**, we present an analytic derivation of the electrical conductivity σ as a function of D for, respectively, the zigzag structures at $D \in (1, 1 + \sqrt{3}/2)$ (**Section 3**), the two types of helical structures at $D < 2$ (**Section 4**), and the double-helix structures at $D \in (2, 1 + 3\sqrt{3}/5)$ (**Section 5**). In **Section 6**, we summarize our results and discuss their implications.

2 RESISTOR-NETWORK MODEL

For any pair of touching spheres with a potential difference $\Delta\psi$ and with a current I that flows from one sphere to the other, the

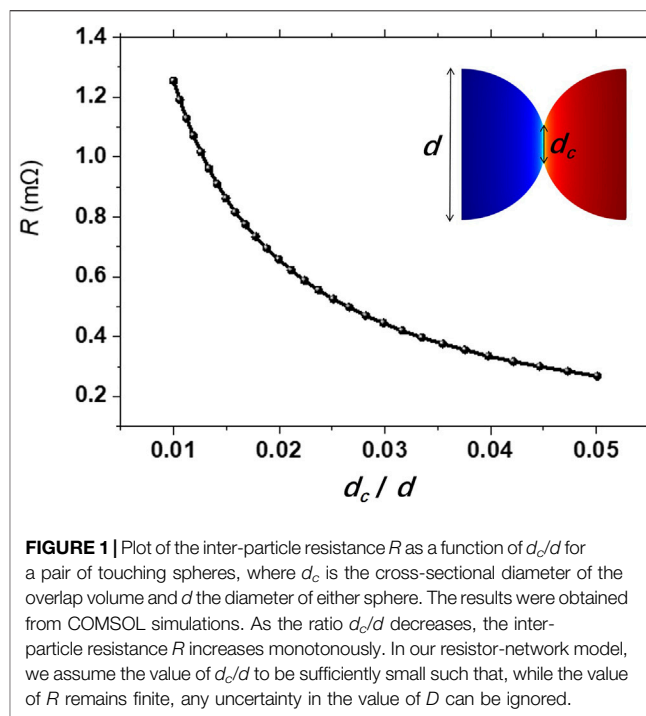


FIGURE 1 | Plot of the inter-particle resistance R as a function of d_c/d for a pair of touching spheres, where d_c is the cross-sectional diameter of the overlap volume and d the diameter of either sphere. The results were obtained from COMSOL simulations. As the ratio d_c/d decreases, the inter-particle resistance R increases monotonously. In our resistor-network model, we assume the value of d_c/d to be sufficiently small such that, while the value of R remains finite, any uncertainty in the value of D can be ignored.

inter-particle resistance R , which takes into account the bulk resistance of each sphere and the contact resistance between the spheres, is defined as

$$R \equiv \left| \frac{\Delta\psi}{I} \right|, \quad (1)$$

and is modelled by a resistor that joins the centres of the spheres. The contact resistance is thought to be arising from a negligibly small overlap between the spheres. Let d_c be the cross-sectional diameter of the overlap volume and d the diameter of either sphere. The ratio d_c/d is then a measure of the extent of inter-sphere overlap. **Figure 1** shows that, as this ratio decreases, the inter-particle resistance R increases monotonously. We assume the value of d_c/d to be sufficiently small such that, while the value of R remains finite, any uncertainty in the value of D can be ignored.

In principle, for such columnar structures, the electrical conductivity σ as a function of D can be derived by considering the spatial distribution of resistors within the confining cylindrical space. For any assembly of identical spheres, we take the value of R to be the same for any pair of touching spheres. Since our focus is on the conducting behaviour of the confined spheres, we simplify our problem by assuming all other regions of the confining cylindrical space to be electrically insulating, such that we only need to be concerned with the conducting paths across the assembly of spheres. For each type of structures, we replace each pair of touching spheres by a resistor, identify the corresponding spatial distribution of resistors, and apply Kirchhoff's laws with some symmetry considerations to derive an analytic expression for the electrical conductivity of an infinitely long structure.

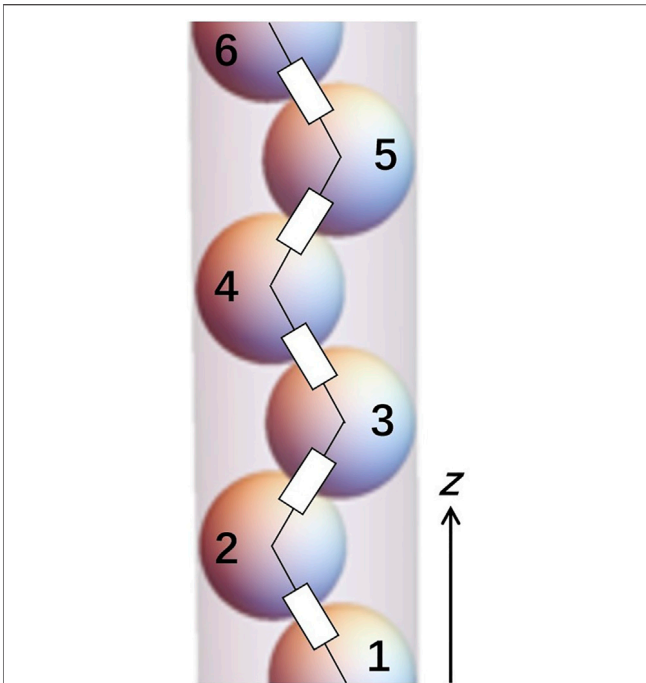


FIGURE 2 | Schematic illustration of a zigzag structure at $D \in (1, 1 + \sqrt{3}/2)$ and the corresponding zigzag chain of resistors. For any pair of touching spheres, the inter-particle resistance R , which takes into account the bulk resistance of each sphere and the contact resistance between the spheres, is modelled by a resistor that joins the centres of the spheres. The diameter of the confining cylindrical tube is just equal to D , if the diameter of each sphere is taken to be unity. The spheres are indexed in ascending order of their vertical z -positions.

3 ZIGZAG STRUCTURES AT $D \in (1, 1 + \sqrt{3}/2)$

Consider the zigzag structures at $D \in (1, 1 + \sqrt{3}/2)$, and assume each of them to be infinitely long. **Figure 2** illustrates such a zigzag structure and the corresponding zigzag chain of resistors. At $D < 2$, the spheres of any columnar structure are distinguishable in terms of their vertical z -positions along the long axis of the cylindrical space. Taking advantage of this, we have indexed the spheres of the abovementioned zigzag structure in ascending order of their vertical positions. Any sphere i in such a zigzag structure is only in contact with its two nearest neighbours, i.e. spheres $(i - 1)$ and $(i + 1)$, such that the corresponding coordination number (C. N.) is 2. For any pair of neighbouring spheres, the centre-to-centre separation along the long axis of the cylindrical space is given by

$$(\Delta z)_D = \sqrt{D(2 - D)}, \tag{2}$$

if the diameter of each sphere is taken to be unity. The electrical conductivity σ as a function of D can be derived by considering an equivalent linear chain of resistors, in which each resistive component occupies a cylindrical space of length $(\Delta z)_D$ and cross-sectional area $A_D = \pi(D/2)^2$:

$$\sigma' \equiv \left(\frac{\pi R}{4}\right)\sigma = \frac{\sqrt{2 - D}}{D^{3/2}} \tag{3}$$

where, for increasing D , the numerator and denominator of this expression for the rescaled conductivity σ' decreases and increases, respectively. This corresponds to a monotonous decrease in σ' , as the columnar structure becomes thicker in diameter and the resistors inside become more densely packed along the long axis of the cylindrical space.

4 SINGLE- AND DOUBLE-HELIX STRUCTURES AT $D < 2$

The single-helix structures at $D \in (1 + \sqrt{3}/2, 1 + 4\sqrt{3}/7)$ and the double-helix structures at $D \in (1 + 4\sqrt{3}/7, 2)$ are different from the zigzag structures at $D \in (1, 1 + \sqrt{3}/2)$ in terms of their networks of inter-particle contacts, and for this reason we classify the zigzag-to-single-helix transition at $D = 1 + \sqrt{3}/2$ as a discontinuous structural transition. On the other hand, these two types of helical structures at $D < 2$ share the same network of inter-particle contacts, and therefore we classify the single-

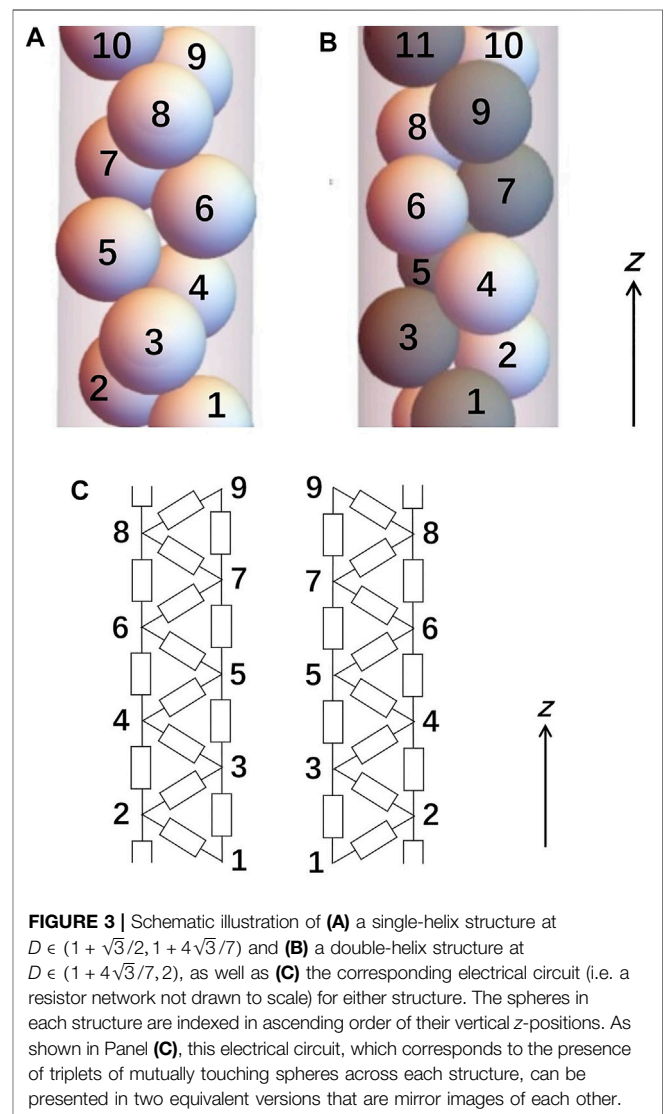


FIGURE 3 | Schematic illustration of (A) a single-helix structure at $D \in (1 + \sqrt{3}/2, 1 + 4\sqrt{3}/7)$ and (B) a double-helix structure at $D \in (1 + 4\sqrt{3}/7, 2)$, as well as (C) the corresponding electrical circuit (i.e. a resistor network not drawn to scale) for either structure. The spheres in each structure are indexed in ascending order of their vertical z -positions. As shown in Panel (C), this electrical circuit, which corresponds to the presence of triplets of mutually touching spheres across each structure, can be presented in two equivalent versions that are mirror images of each other.

helix-to-double-helix transition at $D = 1 + 4\sqrt{3}/7$ as a continuous structural transition. In each of those helical structures, be it a single- or a double-helix structure, each sphere is not only in contact with its two nearest neighbours but also in contact with its two next-nearest neighbours [e.g., sphere i in contact with spheres $(i \pm 1)$ and $(i \pm 2)$] such that, for a coordination number of 4, there exist triplets of mutually touching spheres, in the form of $\{1, 2, 3\}$, $\{2, 3, 4\}$, $\{3, 4, 5\}$. . . , across the structure.

As illustrated in **Figure 3**, with additional resistors joining pairs of next-nearest neighbours, the resistor network of any single- or double-helix structure at $D < 2$ is no longer a simple chain of resistors and is therefore different from that of a zigzag structure. It reflects the presence of triplets of mutually touching spheres in the structure. But based on some symmetry considerations for an infinitely long structure, an equivalent linear chain of resistors can be derived from this more complex resistor network. The electrical conductivity σ as a function of D can then be derived by considering the length and cross-sectional area of the cylindrical space occupied by each resistive component in this equivalent circuit.

Consider the electrical circuit on the left-hand side of **Figure 3C**, and let $I_{i \rightarrow j}$ be the current that flows from sphere i to sphere j . Since this circuit is infinitely long, the circuital environment (i.e., the way a sphere is connected to all other components in the circuit) of sphere $i \in (-\infty, +\infty)$ is the same for respectively all even values of i and all odd values of i as a result of translational symmetry across the circuit. On the other hand, the equivalent mirror-symmetric circuit on the right-hand side of **Figure 3C** implies that the circuital environment is the same for all spheres regardless of whether their indices i are odd or even. It follows that the symmetry conditions

$$I_{i \rightarrow (i+1)} = I_{(i+1) \rightarrow (i+2)} \tag{4}$$

and

$$I_{i \rightarrow (i+2)} = I_{(i+2) \rightarrow (i+4)} \tag{5}$$

apply to any value of i . According to Kirchhoff's current law, the total current that flows into any sphere i is equal to the total current that flows out of the same sphere:

$$I_{\text{total}} = I_{(i-2) \rightarrow i} + I_{(i-1) \rightarrow i} = I_{i \rightarrow (i+1)} + I_{i \rightarrow (i+2)}. \tag{6}$$

This condition also follows naturally from the symmetry conditions $I_{(i-1) \rightarrow i} = I_{i \rightarrow (i+1)}$ and $I_{(i-2) \rightarrow i} = I_{i \rightarrow (i+2)}$, as described respectively by **Eqs 4** and **5**. On the other hand, let $V_{i \rightarrow j} = I_{i \rightarrow j}R$ be the voltage across sphere i and sphere j . According to Kirchhoff's voltage law, the voltage across any pair of spheres is path-independent, so that we can link up the voltages across nearest neighbours and those across next-nearest neighbours as follows:

$$I_{i \rightarrow (i+2)}R = I_{i \rightarrow (i+1)}R + I_{(i+1) \rightarrow (i+2)}R. \tag{7}$$

A combination of **Eqs 4** and **7** yields the following relation between $I_{i \rightarrow (i+1)}$ and $I_{i \rightarrow (i+2)}$:

$$I_{i \rightarrow (i+2)} = 2I_{i \rightarrow (i+1)}, \tag{8}$$

such that the total current that flows across any sphere i is equal to

$$I_{\text{total}} = 3I_{i \rightarrow (i+1)}. \tag{9}$$

For any integer N , the voltage across sphere i and sphere $(i + N)$ is a sum of the voltages across nearest neighbours:

$$V_{i \rightarrow (i+N)} = NV_{i \rightarrow (i+1)} = NI_{i \rightarrow (i+1)}R. \tag{10}$$

This voltage can also be expressed in terms of the effective resistance $R_{i, (i+N)}$ between sphere i and sphere $(i + N)$:

$$V_{i \rightarrow (i+N)} = 3I_{i \rightarrow (i+1)}R_{i, (i+N)}, \tag{11}$$

where, according to **Eq. 9**, $3I_{i \rightarrow (i+1)}$ is the total current that flows across either sphere. A combination of the above expressions for $V_{i \rightarrow (i+N)}$ reveals a simple proportionality between $R_{i, (i+N)}$ and R :

$$R_{i, (i+N)} = \frac{R_{i, (i+N)}}{N} = \frac{R}{3}. \tag{12}$$

It follows that the electrical conductivity of any single- or double-helix structure at $D < 2$ can be obtained from an equivalent linear chain of resistors in which the resistance of each component is equal to $R/3$. For any single-helix structure at $D \in (1 + \sqrt{3}/2, 1 + 4\sqrt{3}/7)$, each resistive component in the equivalent linear chain of resistors occupies a cylindrical space of length [35].

$$(\Delta z)_D = \sqrt{\left(1 + \frac{\sqrt{3}}{2}\right) - \frac{\sqrt{3}}{2}D} \tag{13}$$

and cross-sectional area $A_D = \pi(D/2)^2$, so that the electrical conductivity σ as a function of D is given by

$$\sigma' \equiv \left(\frac{\pi R}{4}\right)\sigma = \frac{3}{\sqrt{2}} \frac{\sqrt{(2 + \sqrt{3}) - \sqrt{3}D}}{D^2}. \tag{14}$$

For the double-helix structures at $D \in (1 + 4\sqrt{3}/7, 2)$, a similar derivation using the condition [35].

$$(\Delta z)_D = \frac{1}{2\sqrt{2}} \sqrt{1 + \sqrt{1 - (D - 1)^2}} \tag{15}$$

yields the following expression for the electrical conductivity as a function of D :

$$\sigma' \equiv \left(\frac{\pi R}{4}\right)\sigma = \frac{3}{2\sqrt{2}} \frac{\sqrt{1 + \sqrt{1 - (D - 1)^2}}}{D^2}. \tag{16}$$

Like the case of zigzag structures, the rescaled conductivity σ' of either type of helical structures at $D < 2$ decreases monotonously for increasing D , as the numerator and denominator in the corresponding expression decreases and increases, respectively.

5 DOUBLE-HELIX STRUCTURES AT $D \in (2, 1 + 3\sqrt{3}/5)$

For the double-helix structures at $D \in (2, 1 + 3\sqrt{3}/5)$, the electrical conductivity σ as a function of D can be derived in a manner similar to that for the two types of helical structures at

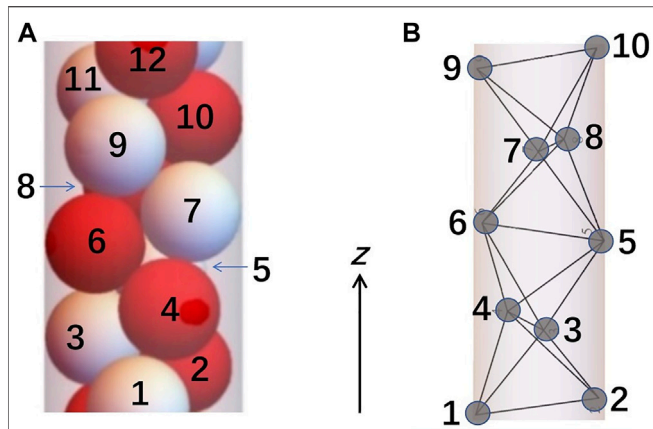


FIGURE 4 | Schematic illustration of **(A)** a double-helix structure at $D \in (2, 1 + 3\sqrt{3}/5)$ and **(B)** the corresponding network of inter-particle contacts. The spheres in the structure are indexed in ascending order of their vertical z -positions. Each sphere is not only in contact with its two nearest neighbours and two next-nearest neighbours but also with one of its third-nearest neighbours, such that there exist quartets of mutually touching spheres, in the form of $\{1, 2, 3, 4\}$, $\{3, 4, 5, 6\}$, $\{5, 6, 7, 8\}$... across the structure.

$D < 2$. Here we need to consider a slightly different resistor network (**Figure 4**), because each sphere in such a double-helix structure is not only in contact with its two nearest neighbours and two next-nearest neighbours but also with one of its third-nearest neighbours (C. N. = 5). Take the structure in **Figure 4** as an example. For any odd value of i , sphere i is in contact with sphere $(i + 3)$, such that the consecutive quartet of spheres, $\{i, (i + 1), (i + 2), (i + 3)\}$, are in mutual contact and exhibit a tetrahedral configuration. This gives rise to the presence of quartets of mutually touching spheres, in the form of $\{1, 2, 3, 4\}$, $\{3, 4, 5, 6\}$, $\{5, 6, 7, 8\}$... across the structure. Since sphere $(i + 1)$ is not in contact with sphere $(i + 4)$, the circuitual environment of sphere i is different from that of sphere $(i + 1)$, such that we should only consider the following conditions of translational symmetry for pairs of next-nearest neighbours:

$$I_{i \rightarrow (i+1)} = I_{(i+2) \rightarrow (i+3)}, \tag{17}$$

$$I_{i \rightarrow (i+2)} = I_{(i+2) \rightarrow (i+4)} \tag{18}$$

and

$$I_{i \rightarrow (i+3)} = I_{(i+2) \rightarrow (i+5)}. \tag{19}$$

According to Kirchhoff's current law, the total current that flows across sphere i is given by

$$I_{\text{total}} = I_{(i-2) \rightarrow i} + I_{(i-1) \rightarrow i} = \sum_{n=1}^3 I_{i \rightarrow (i+n)}, \tag{20}$$

which can also be written as

$$I_{\text{total}} = I_{i \rightarrow (i+2)} + I_{(i+1) \rightarrow (i+2)} = \sum_{n=1}^3 I_{i \rightarrow (i+n)} \tag{21}$$

according to the above symmetry conditions for next-nearest neighbours. This implies

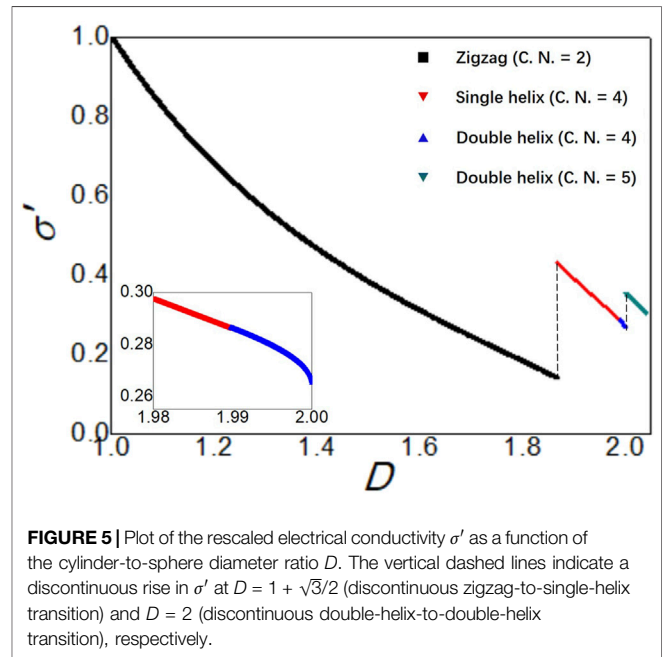


FIGURE 5 | Plot of the rescaled electrical conductivity σ' as a function of the cylinder-to-sphere diameter ratio D . The vertical dashed lines indicate a discontinuous rise in σ' at $D = 1 + \sqrt{3}/2$ (discontinuous zigzag-to-single-helix transition) and $D = 2$ (discontinuous double-helix-to-double-helix transition), respectively.

$$I_{i \rightarrow (i+1)} + I_{i \rightarrow (i+3)} = I_{(i+1) \rightarrow (i+2)}. \tag{22}$$

On the other hand, according to Kirchhoff's voltage law, we have the following conditions for the path independence of voltages:

$$V_{i \rightarrow (i+3)} = I_{i \rightarrow (i+3)}R = \sum_{n=1}^3 I_{(i-1+n) \rightarrow (i+n)}R \tag{23}$$

and

$$V_{i \rightarrow (i+2)} = I_{i \rightarrow (i+2)}R = I_{i \rightarrow (i+1)}R + I_{(i+1) \rightarrow (i+2)}R. \tag{24}$$

Using the symmetry condition $I_{(i+2) \rightarrow (i+3)} = I_{i \rightarrow (i+1)}$, **Eq. 23** can be written as

$$I_{i \rightarrow (i+3)}R = 2I_{i \rightarrow (i+1)}R + I_{(i+1) \rightarrow (i+2)}R. \tag{25}$$

Substituting **Eq. 34** into **Eq. 22** yields

$$I_{i \rightarrow (i+1)} = 0, \tag{26}$$

which implies

$$I_{i \rightarrow (i+2)} = I_{(i+1) \rightarrow (i+2)} \tag{27}$$

and hence

$$I_{\text{total}} = 2I_{i \rightarrow (i+2)} \tag{28}$$

according to **Eqs 21** and **24**, respectively. For any integer N , the voltage across sphere i and sphere $(i + 2N)$ is a sum of the voltages across next-nearest neighbours:

$$V_{i \rightarrow (i+2N)} = NV_{i \rightarrow (i+2)} = NI_{i \rightarrow (i+2)}R. \tag{29}$$

This voltage can also be expressed in terms of the effective resistance $R_{i, (i+2N)}$ between sphere i and sphere $(i + 2N)$:

$$V_{i \rightarrow (i+2N)} = 2I_{i \rightarrow (i+2)}R_{i, (i+2N)} \tag{30}$$

for $I_{\text{total}} = 2I_{i \rightarrow (i+2)}$. A combination of **Eqs 29** and **30** yields

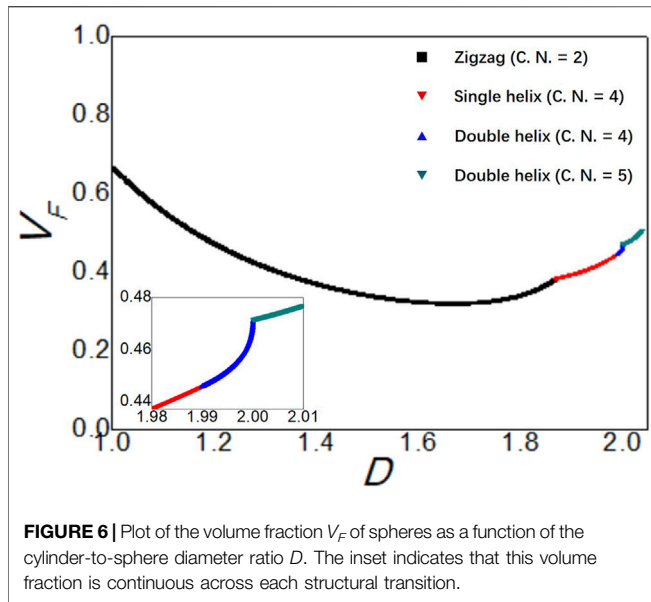


FIGURE 6 | Plot of the volume fraction V_F of spheres as a function of the cylinder-to-sphere diameter ratio D . The inset indicates that this volume fraction is continuous across each structural transition.

$$R_{i,(i+1)} \equiv \frac{R_{i,(i+2N)}}{2N} = \frac{R}{4}. \quad (31)$$

According to Eqs 12 and 31, there is a drop in the effective resistance $R_{i,(i+1)}$ as the diameter ratio D increases beyond 2. This is attributed to the establishment of additional conducting paths across the system. For this type of helical structures, we have [69].

$$(\Delta z)_D = \frac{\sqrt{1 + \sqrt{9 - 8(D - 1)^2}}}{4}. \quad (32)$$

The electrical conductivity σ as a function of D is then given by

$$\sigma' \equiv \left(\frac{\pi R}{4}\right)\sigma = \frac{\sqrt{1 + \sqrt{9 - 8(D - 1)^2}}}{D^2}, \quad (33)$$

where, as in the case of the other types of structures, the rescaled conductivity σ' decreases monotonously for increasing D .

6 RESULTS AND DISCUSSION

The rescaled electrical conductivity σ' as a function of D has been derived for the zigzag structures at $D \in (1, 1 + \sqrt{3}/2)$, the single-helix structures at $D \in (1 + \sqrt{3}/2, 1 + 4\sqrt{3}/7)$, the double-helix structures at $D \in (1 + 4\sqrt{3}/7, 2)$, and the double-helix structures at $D \in (2, 1 + 3\sqrt{3}/5)$. From the results, we have also found out how σ' is related to the volume fraction V_F of spheres. As shown in Figure 5, for increasing D , the rescaled electrical conductivity σ' decreases monotonously for each type of structures, as the resistive components of the system become more densely packed along the long axis of the cylindrical space. However, there exists a discontinuous rise in σ' at $D = 1 + \sqrt{3}/2$ (discontinuous zigzag-to-single-helix transition) and $D = 2$ (discontinuous double-helix-to-double-helix transition), respectively, as a result of the establishment of additional conducting paths upon an abrupt increase in the number of

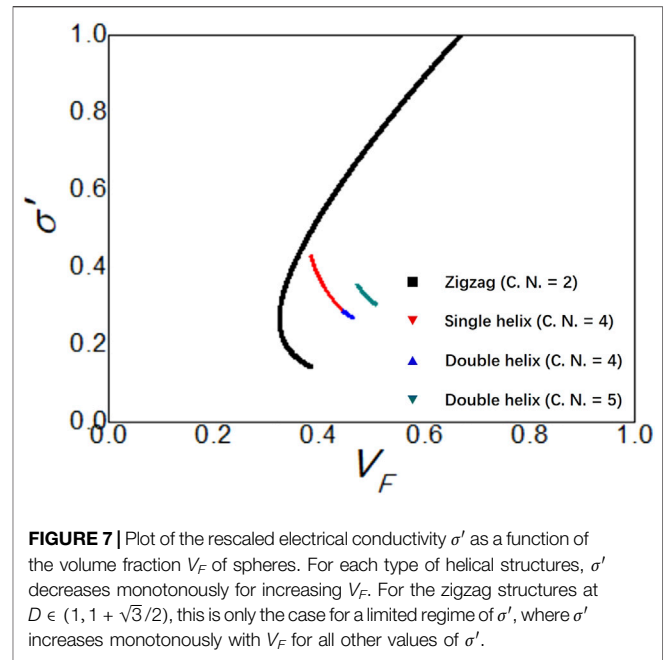


FIGURE 7 | Plot of the rescaled electrical conductivity σ' as a function of the volume fraction V_F of spheres. For each type of helical structures, σ' decreases monotonously for increasing V_F . For the zigzag structures at $D \in (1, 1 + \sqrt{3}/2)$, this is only the case for a limited regime of σ' , where σ' increases monotonously with V_F for all other values of σ' .

inter-particle contacts. This is not the case for the continuous single-helix-to-double-helix transition at $D = 1 + 4\sqrt{3}/7$. Figure 6 shows an auxiliary plot of the volume fraction V_F of spheres as a function of D , where for each type of structures this volume fraction is given by [23].

$$V_F = \frac{2}{3D^2(\Delta z)_D}. \quad (34)$$

As indicated by the inset of Figure 6, this volume fraction is continuous across every structural transition, as different from the case of σ' . Figure 7 shows a plot of σ' as a function of V_F . It was found that, for each type of helical structures, the rescaled electrical conductivity σ' decreases monotonously for increasing V_F . For the zigzag structures at $D \in (1, 1 + \sqrt{3}/2)$, however, this is only the case for a limited regime of σ' , where σ' increases monotonously with V_F for all other values of σ' .

The results presented in Figure 5 could serve as a guide for the development of quasi-one-dimensional materials with a structurally tunable electrical conductivity. Any such experimental system should be a densest-packed assembly of conducting spherical particles immersed in an insulating medium. Once the inter-particle resistance R between any pair of touching spheres is known, the system's electrical conductivity can be tuned to any designated value through a variation of D . On the other hand, the relation between σ' and V_F as presented in Figure 7 suggests that it is possible to characterise the volume fraction experimentally by means of electrical-conductivity measurements. In cases where the measured value of σ' corresponds to two possible values of V_F , i.e. to two possible types of columnar structures, the correct type of structures can be determined from the corresponding measured value of D .

DATA AVAILABILITY STATEMENT

The original contributions of this study are all included in the article. Further inquiries can be directed to the corresponding author.

AUTHOR CONTRIBUTIONS

This research was jointly completed by PM and her research supervisor H-KC. The manuscript was mainly written up by H-KC.

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